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Kind regards,

Team Nexperia



PUMX1

40 V, 100 mA NPN/NPN general-purpose transistor Rev. 04 — 20 January 2010 Produ

Product data sheet

Product profile

1.1 General description

NPN/NPN general-purpose transistor with two independently operating transistors in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview**

Type number	Package		PNP/PNP	NPN/PNP	
	NXP	JEITA	complement	complement	
PUMX1	SOT363	SC-88	PUMT1	PUMZ1	

1.2 Features

- Double general-purpose transistor
- Board-space reduction
- Very small SMD plastic package

1.3 Applications

General-purpose switching and amplification

Pinning information 2.

Table 2 Dinning

Pin Description 1 emitter TR1 2 base TR1 3 collector TR2 4 emitter TR2 5 base TR2 6 collector TR1	Table 2.	i iiiiiiig		
2 base TR1 3 collector TR2 4 emitter TR2 5 base TR2 6 collector TR1	Pin	Description	Simplified outline	Graphic symbol
base TR1 collector TR2 emitter TR2 base TR2 collector TR1	1	emitter TR1		
4 emitter TR2 5 base TR2 6 collector TR1	2	base TR1		6 5 4
4 emitter TR2 5 base TR2 6 collector TR1	3	collector TR2		TB2
6 collector TR1	4	emitter TR2	0	
6 collector TR1	5	base TR2	□1 □2 □3	
sym020	6	collector TR1		1 2 3
				sym020





40 V, 100 mA NPN general-purpose double transistor

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMX1	SC-88	plastic surface-mounted package; 6 leads	SOT363

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PUMX1	Z*Z

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit			
Per transis	Per transistor							
V_{CBO}	collector-base voltage	open emitter	-	50	V			
V_{CEO}	collector-emitter voltage	open base	-	40	V			
V_{EBO}	emitter-base voltage	open collector	-	5	V			
I _C	collector current		-	100	mA			
I _{CM}	peak collector current		-	200	mA			
I_{BM}	peak base current		-	200	mA			
P _{tot}	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$	-	200	mW			
Per device)							
P _{tot}	total power dissipation	$T_{amb} \leq 25~^{\circ}C$	<u>[1]</u> -	300	mW			
T _j	junction temperature		-	150	°C			
T _{amb}	ambient temperature		-65	+150	°C			
T_{stg}	storage temperature		-65	+150	°C			

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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40 V, 100 mA NPN general-purpose double transistor

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device	•					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	416	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

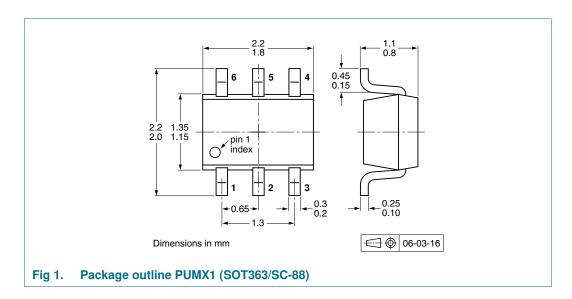
T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	istor					
I _{CBO}	collector-base cut-off current	$V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A}$	-	-	100	nA
		$V_{CB} = 30 \text{ V};$ $I_{E} = 0 \text{ A};$ $T_{j} = 150 \text{ °C}$	-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 4 V;$ $I_C = 0 A$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 6 V;$ $I_{C} = 1 mA$	120	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA};$ $I_B = 5 \text{ mA}$	[1] -	-	200	mV
f _T	transition frequency	$I_{C} = 2 \text{ mA};$ $V_{CE} = 12 \text{ V};$ f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 12 V;$ $I_E = i_e = 0 A;$ $f = 1 MHz$	-	-	1.5	pF

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

40 V, 100 mA NPN general-purpose double transistor

8. Package outline



9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	,, , , , , , , , , , , , , , , , , , ,			Packing qua	ntity
number				3000	10000
PUMX1 SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135	
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

^[1] For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping



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10. Revision history

Table 9. Revision history

	•					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
PUMX1_4	20100120	Product data sheet	-	PUMX1_3		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	<u>Table 1 "Product overview"</u> : added					
	Section 1.2 "Features": updated					
	Section 1.3 "Applications": amended					
	Section 2 "Pinning information": amended					
	 Figure 1: superseded by minimized package outline drawing 					
	Section 9 "Packing information": added					
	Section 11	"Legal information": updated				
PUMX1_3	19990414	Preliminary specification	-	PUMX1_2		
PUMX1_2	19970709	Preliminary specification	-	PUMX1_1		
-						

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11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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